
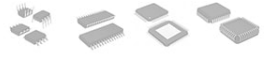

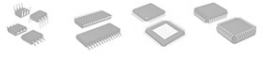

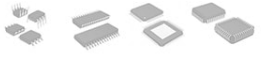



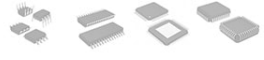


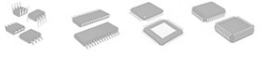

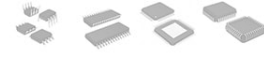


	<h2>MSM51V18165F-60T3</h2>
	<p><b>codice articolo del costruttore:</b> <a href="#">MSM51V18165F-60T3</a></p> <hr/> <p><b>Costruttore / Marca:</b> <a href="#">LAPIS Semiconductor</a></p> <hr/> <p><b>Parte della descrizione:</b> IC DRAM 16MBIT 60NS 50TSOP</p> <hr/> <p><b>Schede tecniche:</b>  <a href="#">MSM51V18165F-60T3.pdf</a></p> <hr/> <p><b>Stato di RoHS:</b> Senza piombo / RoHS conforme</p> <hr/> <p><b>Condizione di scorta:</b> New original, 2597 pcs Stock Available.</p> <hr/> <p><b>Nave da:</b> Hong Kong</p> <hr/> <p><b>Modo di spedizione:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### specificazioni


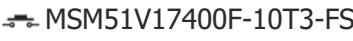
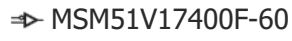
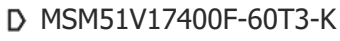
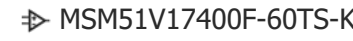

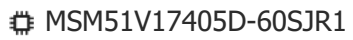
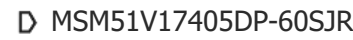

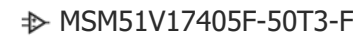

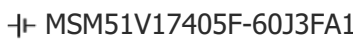
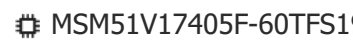

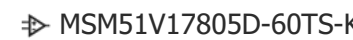
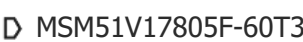
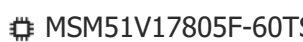
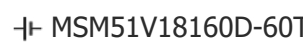
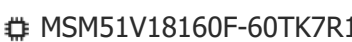
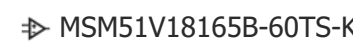
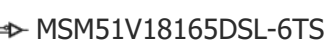

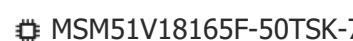

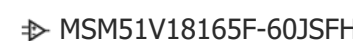

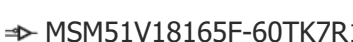
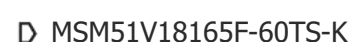

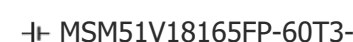







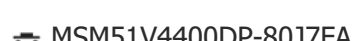






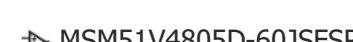





Numero di parte	MSM51V18165F-60T3
fabbricante	LAPIS Semiconductor
Descrizione	IC DRAM 16MBIT 60NS 50TSOP
Categoria	<a href="#">Circuiti integrati (CI) &gt; Memoria</a>
Stato parte	2597 pcs Stock
Serie	-
temperatura di esercizio	0°C ~ 70°C (TA)
Interfaccia	Parallel
Contenitore / involucro	50-TSOP (0.400", 10.16mm Width)
Contenitore dispositivo fornitore	50-TSOP
Tensione di alimentazione -	3 V ~ 3.6 V
Tipo di memoria	Volatile
Velocità	60ns
Dimensione della memoria	16Mb (1M x 16)
Formato di memoria	DRAM
imballaggio	Tray

Potresti essere anche interessato:

 <p>Not Actual Photo YIC International Co., Limited.</p>  <p><b>MSM51V18165F-60T3-K</b> OKI MSM51V18165F-60T3-K OKI</p>	 <p>Not Actual Photo YIC International Co., Limited.</p>  <p><b>MSM51V18165F-60J3</b> OKI MSM51V18165F-60J3 OKI</p>	 <p>Not Actual Photo YIC International Co., Limited.</p>  <p><b>MSM51V18165F-60TS</b> OKI MSM51V18165F-60TS OKI</p>	 <p>Not Actual Photo YIC International Co., Limited.</p>  <p><b>MSM51V18165F-60TS-K</b> OKI MSM51V18165F-60TS-K OKI</p>
 <p>Not Actual Photo YIC International Co., Limited.</p>  <p><b>MSM51V18165F-60TSKR1</b> OKI MSM51V18165F-60TSKR1 OKI</p>	 <p><b>MSM51V18165F-60J3-7</b> LAPIS Semiconductor IC DRAM 16MBIT 60NS 42SOJ</p>	 <p>Not Actual Photo YIC International Co., Limited.</p>  <p><b>MSM51V18165F-60TK7R1</b> OKI MSM51V18165F-60TK7R1 OKI</p>	 <p>Not Actual Photo YIC International Co., Limited.</p>  <p><b>MSM51V18165F-60JS</b> OKI MSM51V18165F-60JS OKI</p>

### Hot Parts

Di Più

Contact us: [Info@YIC-Electronics.com](mailto:Info@YIC-Electronics.com)

AGGIUNGI: Unità A5-B5 n. 509, 5 / F Sing Win Factory Building, 15-17 Shing Yip St, Kwun Tong, Kowloon, Hong Kong.

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